NSN 5961-01-116-5609

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View Online at https://aerobasegroup.com/nsn/5961-01-116-5609 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Function For Which Designed:** Rectifier **End Application:** 1430-01-087-6337 **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.031 inches and 1.064 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 75.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unef **Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 1 threaded stud **Specification Data:** 81349-mil-prf-19500/246 government specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.